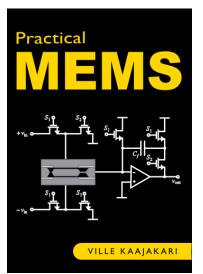
Practical MEMS

Chapter 3: Accelerometers

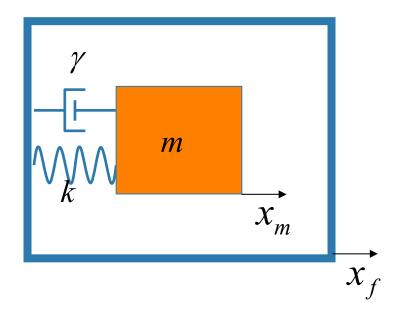


http://www.kaajakari.net/PracticalMEMS

Micromachined accelerometers

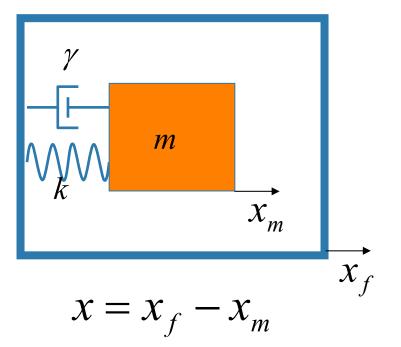
- The "second" MEMS product (first was pressure sensors).
- Applications:
 - Crash detectors for air bag deployment. Over 6,000 lives saved in US.
 - Low-G sensors are used for active suspensions and vehicle stabilization controls.
 - Motion based user interfaces (e.g. game consoles, cell phones)
 - Step counters, running speed and distance.
 - Digital cameras to determine the picture orientation.
 - Free fall detection to protect laptop hard drives

Principle of operation



- A proof mass is attached to frame with a spring.
- When the frame is accelerated, the proof mass follows the frame motion with a lag.

Frequency response



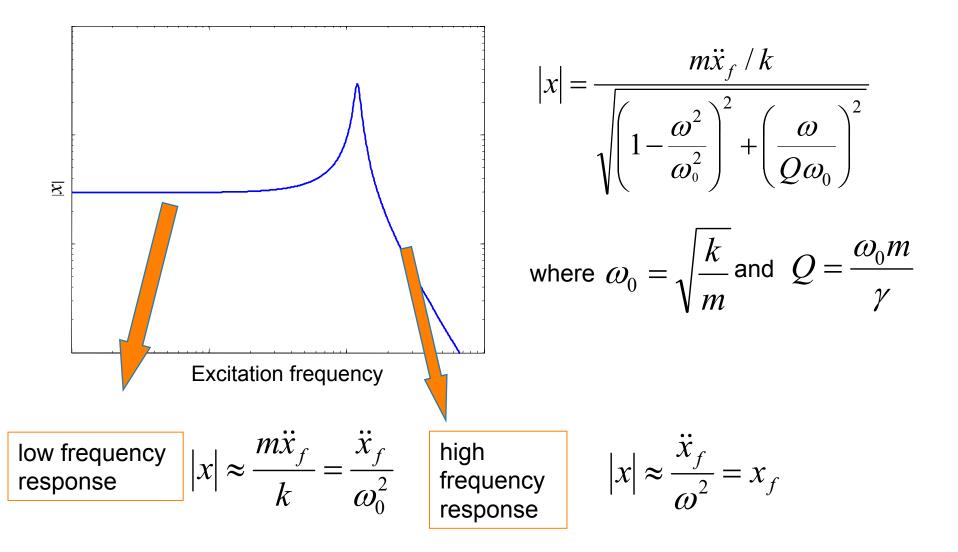
Equation of motion:

$$m\frac{\partial^2 x}{\partial t^2} + \gamma \frac{\partial x}{\partial t} + kx = m\ddot{x}_f$$

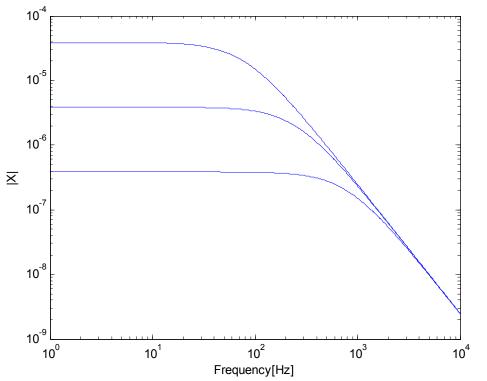
$$x = \frac{m\ddot{x}_f}{s^2 m + s\gamma + k}$$

The proof mass displacement relative to the frame is proportional to the acceleration!

Amplitude of the response

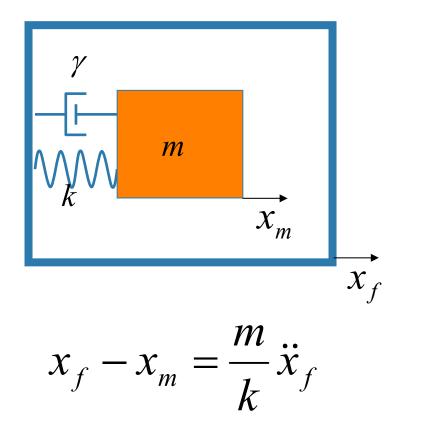


Changing the resonant frequency

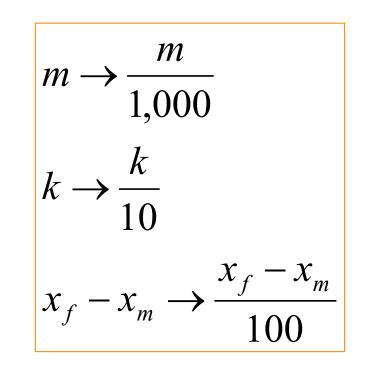


- •Lowering ω_0 improves low frequency response but does not affect high frequency response.
- •Overall, lowering ω_0 helps.
- •Taken to extreme $\omega_0 = 1-2$ Hz! (Macroscopic seismometers).
- •For MEMS typically $\omega_0 > 50$ HZ.

Scaling laws for accelerometers

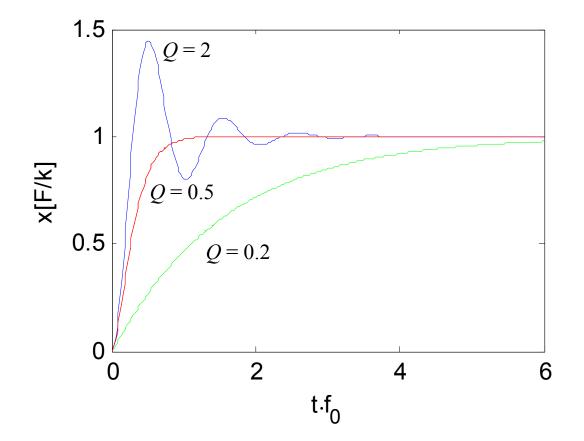


What happens when all dimensions are reduced 10x?



(Analog devices accelerometers measure 0.1 Å displacements!)

Time domain response

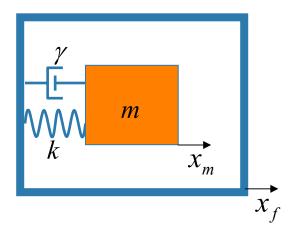


Critical damping or over damping preferred for clean response

Sensing principles

- Piezoresistive
 - Stress sensitive resistors integrated in the springs
 - Robust
 - Noisy, high power, and large temperature dependency
- Capacitive
 - Direct measurement of displacement
 - Low power, low noise
 - Small capacitance measurement is difficult
- Piezoelectric
 - Self generating
 - Signal proportional to change in stress no dc signal!
- Magnetic
- Optical

Noise equivalent acceleration (spectral density)



Equate noise force generator and apparent acceleration force :

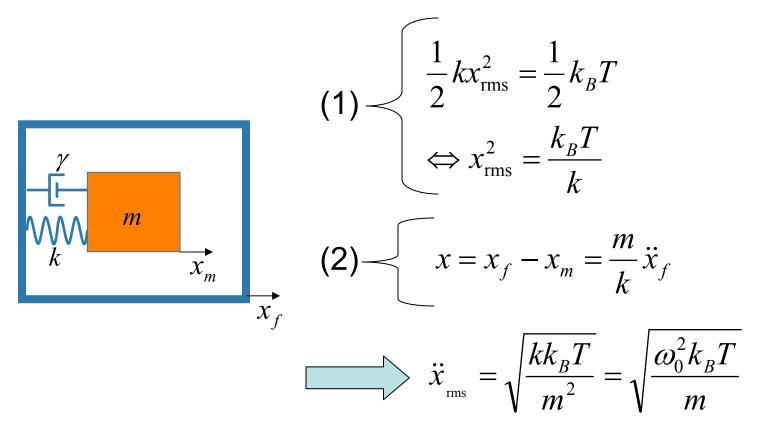
$$\overline{F}_n = \sqrt{4k_B T \gamma}$$

$$F_{\ddot{x}} = m\ddot{x}$$

Noise equivalent acceleration :

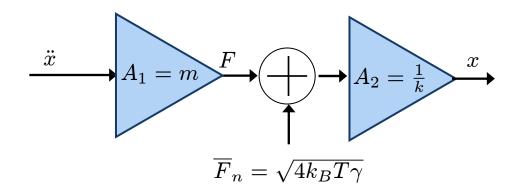
$$\overline{\ddot{x}_n} = \sqrt{\frac{4k_B T \omega_0}{mQ}} \quad \left[\frac{m/s^2}{\sqrt{Hz}} \right]$$

Noise equivalent acceleration (rms acceleration)

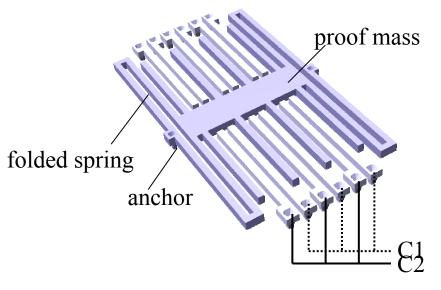


Total rms noise depends only on mass and resonant frequency!

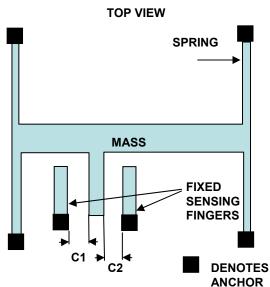
System level noise model

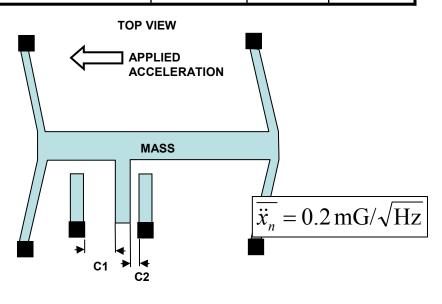


Surface micromachined accelerometer



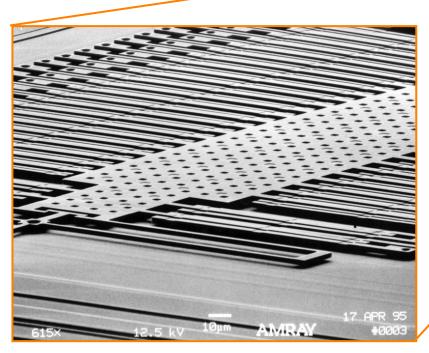
Parameter	Symbol	Value	Units
Resonant frequency	f_0	22	kHz
Mass	т	0.1	nkg
Spring constant	k	2	N/m
Electrode capacitance	<i>C</i> ₀	0.1	pF
Quality factor	Q	3-4	

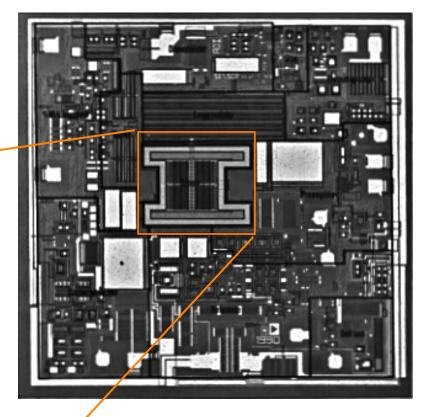




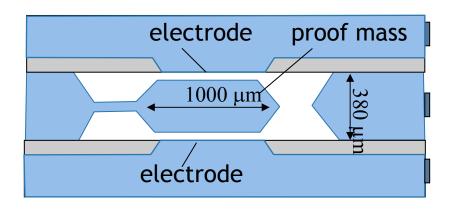
ADXL50 Accelerometer

- +/-50G
- Polysilicon MEMS & BiCMOS
- 3x3mm die





Bulk micromachined accelerometer



Parameter	Symbol	Value	Units
Resonant frequency	f_0	1	kHz
Mass	т	1	μ kg
Spring constant	k	50	N/m
Electrode capacitance	<i>C</i> ₀	5	pF
Quality factor	Q	0.1	

Noise equivalent acceleration : $\vec{x}_n = 3 \,\mu \text{G} / \sqrt{\text{Hz}}$